

IPP100N04S4H2AKSA1

IPP100N04S4H2AKSA1 Information



umber	IPP100N04S4H2AKSA1
acturer	Infineon Technologies
ory	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
ption	MOSFET N-CH 40V 100A TO220-3-1
ge	TO-220-3
	For the pricing/inventory/lead time, please contact
	us
	Website: https://www.heisener.com
	E-mail: salesdept@heisener.com





For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPP100N04S4H2AKSA1 Specifications

Manufacturer Part Number	IPP100N04S4H2AKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	40V
Current - Continuous Drain (Id) @ 25°C	100A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 70µA
Gate Charge (Qg) (Max) @ Vgs	90nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	7180pF @ 25V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	115W (Tc)
Rds On (Max) @ Id, Vgs	2.7 mOhm @ 100A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO220-3-1
Package / Case	TO-220-3
	Report errors?

IPP100N04S4H2AKSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPP100N04S4H2AKSA1 Payment Methods





If you have any question about IPP100N04S4H2AKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com